

Fundamentals of Building Integrated Photovoltaics

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Outline

- 1. Introduction
- 2. Reference books
- 3. Important parameters
- 4. PV technology materials
- 5. Current status
- 6. BAPV and BIPV definition
- 7. Market development & drivers for BIPV
- 8. BIPV multi-functionality
- 9. Advantages/barriers of BIPV
- 10. BIPV products
- 11. BIPV characteristics
- 12. Case studies
- 13. Conclusions



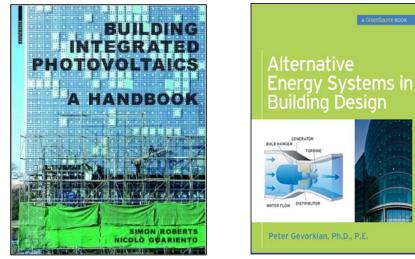






Reference books

- S. Roberts and N. Guariento, Building Integrated Photovoltaics A Handbook, Birkhäuser Architecture; 1st Edition (2009).
- Alternative Energy Systems in Building Design, P. Gevorkian, McGraw-Hill's Greensource Series, 2010







One of the World's Largest PV Parks Agua Caliente, Arizona, USA (290 MWp)







But also utilizing the real advantages of PV





And making PV part of our built environment



01/04/2019



Challenges for PV

- Cost
- Efficiency/Energy yield
- Reliability
- Grid/Market integration









Motivation: Energy Efficiency & NZEBs

Why are we interested in Energy Efficiency and NZEB?

• Buildings responsible for approx. 40% of the total annual energy consumption in Europe.

Buildings \rightarrow major contribution to:

- final energy consumption (>40% EU, 37% CY)
- GHG emissions (>30%)

High financial & environmental cost

Significant potential for:

- energy savings
- GHG emission reduction









PV systems in Cyprus

In Cyprus an average yearly solar irradiation (at the plane of array of 30°) of 2000 kWh/m²/yr yields for a 1 kW PV system at fixed inclination angle of 30° approximately **1700 kWh/kW/yr**



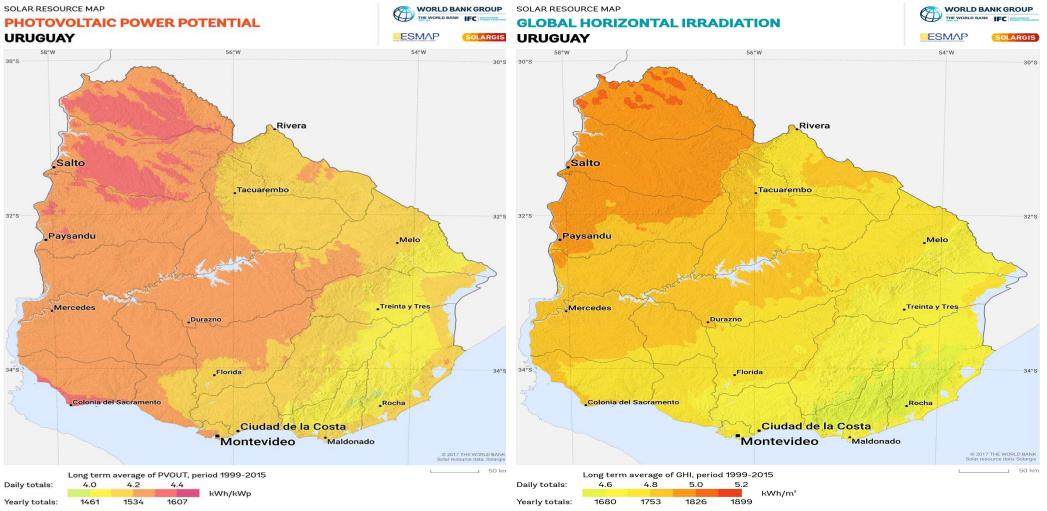
Over a yearly period 2000 kWh/m²/yr

Electricity yearly = Solar irradiation $\times PR \times System$ Power = 2000 $\times 0.85 \times 1$ = 1700 Over a yearly period **1700 kWh/kW/yr**

Conservative case provided by many installers as a lower threshold: **1500 kWh/kW/yr**







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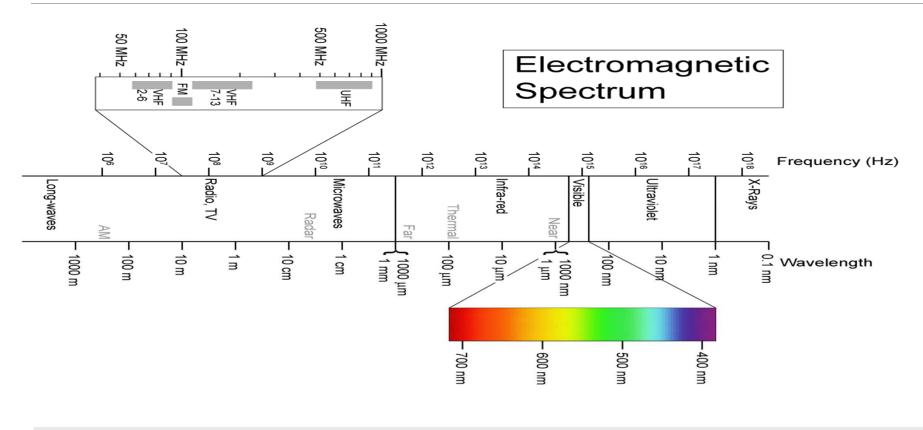
Data for Uruguay (Montevideo)

- Lattitude: 35°S
- Longitude: 56°W
- Global Annual Horizontal Irradiation: 1700 kWh/m²
- PV out: 1500 kWh/kWp





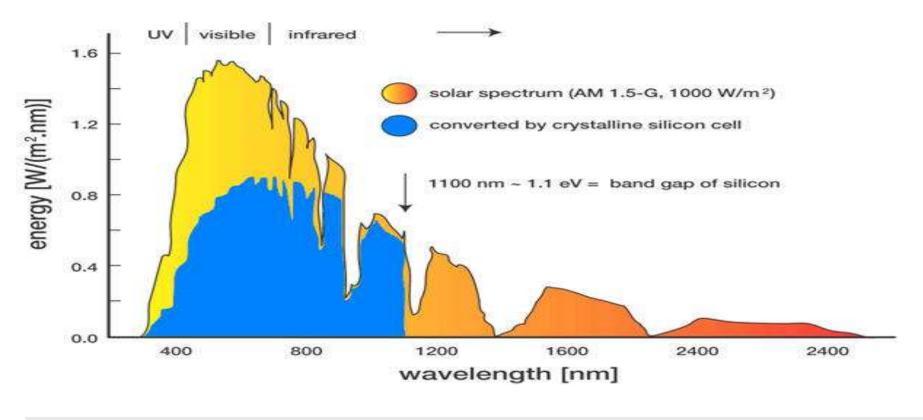
Electromagnetic Spectrum







Solar Spectrum



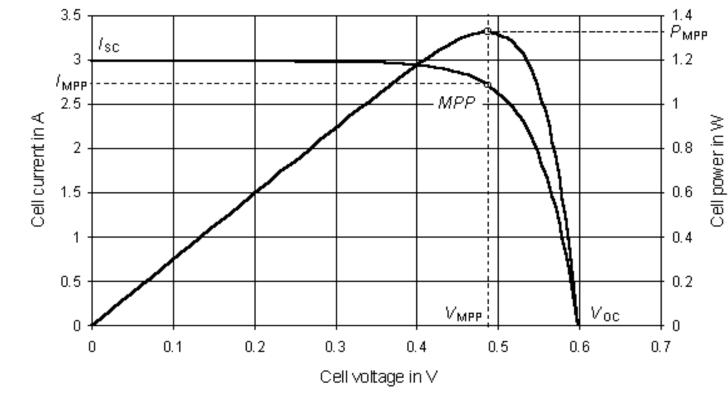
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#### **Important Parameters**

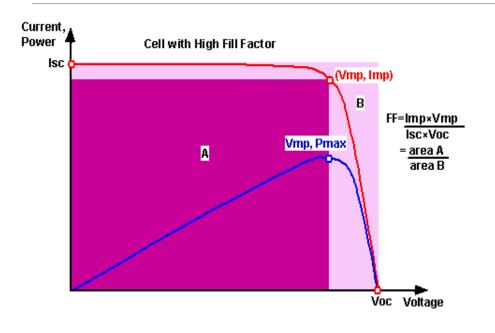
Short Circuit Current (Isc) Open Circuit Voltage (Voc) Maximum Power (Pmpp) Efficiency (η) Fill Factor Performance Ratio (PR) Temperature Coefficients Standard Test Conditions







# Efficiency, Fill Factor and Performance Ratio



$$FF = \frac{V_{MPP} \times I_{MPP}}{V_{OC} \times I_{SC}}$$

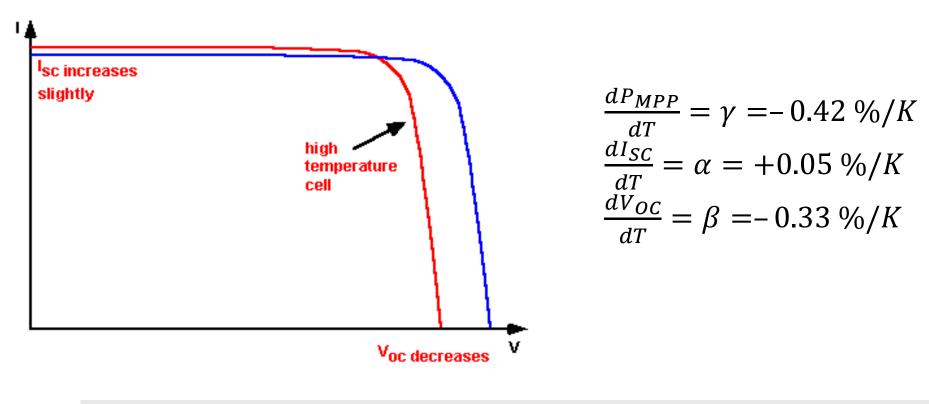
$$\eta = \frac{P_{MPP}}{G \times Area}$$

 $PR = \frac{Actual \ Energy \ Yield}{Ideal \ Energy \ Yield}$ 





# **Temperature Coefficients**



01/04/2019





# **Standard Test Conditions**

- The most common way to compare modules is by their peak-power specification given as watts peak or Wp.
- This rating is made at a well-defined set of conditions known as standard test conditions (STC):
  - the actual temperature of the PV cells (25 °C),
  - the intensity of irradiance (1 kW/m²), the spectral distribution of the light (air mass 1.5 or AM 1.5, the spectrum of sunlight that has been filtered by passing through 1.5 thicknesses of the earth's atmosphere).





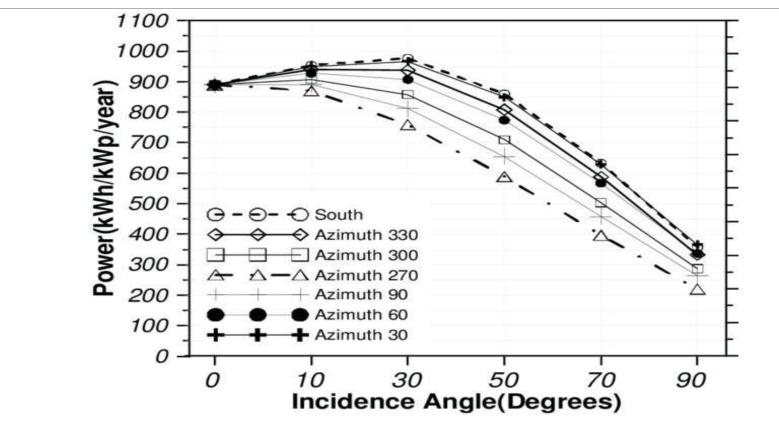
# Nominal Operating Cell Temperature (NOCT)

- Irradiance level of 800 W/m²
- Ambient temperature of 20 °C
- Wind velocity of 1 m/s
- Open rack.





#### Power output as a function of the angle of incidence



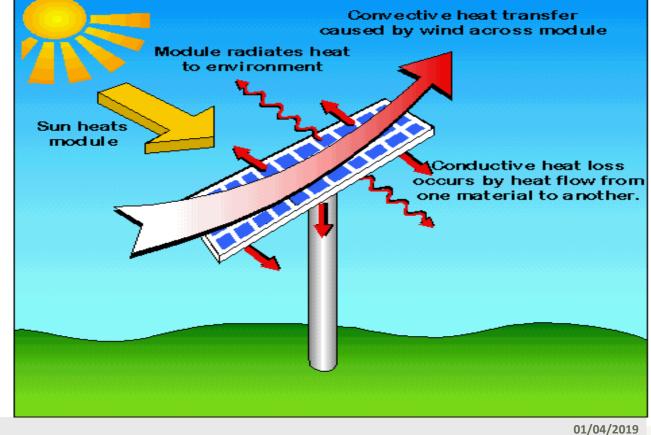
Source: Power Output Characteristics of Transparent a-Si BiPV Window Module, Solar Cells - Thin-Film Technologies



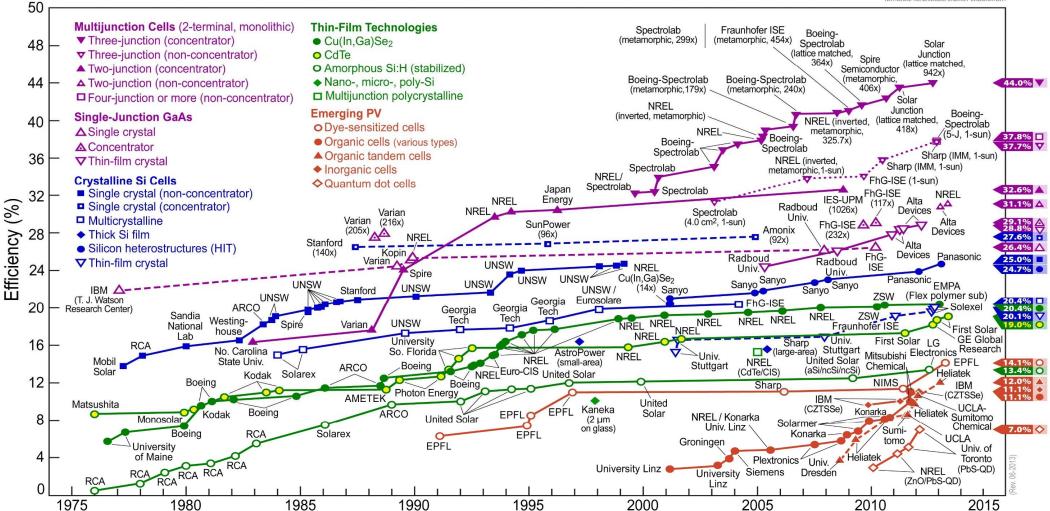


# Heat Loss

- Conduction
- Convection
- Radiation



#### **Best Research-Cell Efficiencies**



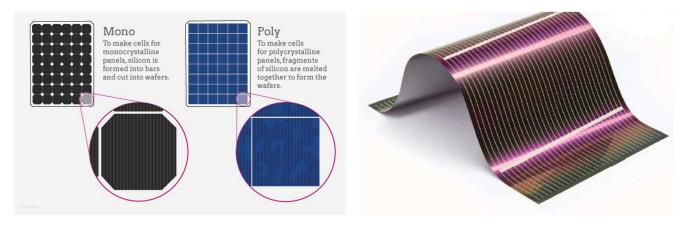






#### PV technology materials

- The active materials of PV cells can be classified:
  - Crystalline Silicon (mono/polycrystalline Silicon):
     sliced from ingots or castings or grown as thin slices from ribbons.
  - Thin-film: deposited as a thin layer on a low cost backing.
- In 2017, 95% of the world PV market was crystalline silicon.









# PV technology materials: Monocrystalline Silicon cells

- Usually manufactured from a single crystal ingot of high purity, most commonly grown by the Czochralski method (crucible process).
- Diameter: 12.5 or 15 cm (4 or 5 inches).
- Ingot is cut into thin slices which are processed to make PV cells.
- The circular shape is cut away for better packing into a module.
- Cell shapes produced can be round, semi-round or square.









### PV technology materials: Polycrystalline Silicon cells

- Alternative way of silicon PV cells.
- The starting material is melted and cast in a cuboid form.
- As the silicon solidifies, large crystals are formed with grain sizes from a few millimetres to a few centimetres.
- Ingot is cut into bars and then sliced into thin wafers that are used to make the cells, similar to the completion of single crystal cells.
- Slightly less expensive than Monocrystalline Silicon but also slightly less efficient.









# PV technology materials: Thin-film cells

- Constructed by depositing extremely thin layers of PV materials onto a superstrate (front glass) or onto a substrate (module backside).
- Connections between the cells are an integral part of the cell fabrication so the PV module is made at the same time.
- Amorphous Silicon (a-Si), Copper Indium Diselenide (CIS) and Cadmium Telluride (CdTe) are used as the active semiconductor materials.
- Lower material and energy consumption and capability for high automation of module production offer considerable cost savings.
- However, efficiency is lower than for crystalline silicon technology.









#### **Current status**

- Currently, most PV modules are installed on roofs/facades using a metal structure.
- PV system: Additional or applied structural element with the sole function of generating energy.









#### **Current status**

• In contrast, increasing application of PVs in which the system, as well as having the function of producing electricity, also takes on the role of a building element.



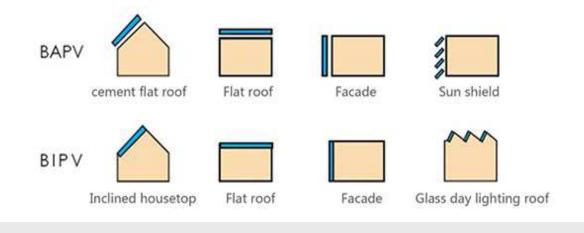
PV is the roof!







- BAPV (Building Applied Photovoltaics):
  - regular PV systems that are generally installed on top of roofs.
- BIPV (Building Integrated Photovoltaics):
  - PV systems integrated into the building envelope elements, such as construction materials as roof tiles and ceramic or glass facades.









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  - regular PV systems that are generally installed on top of roofs.

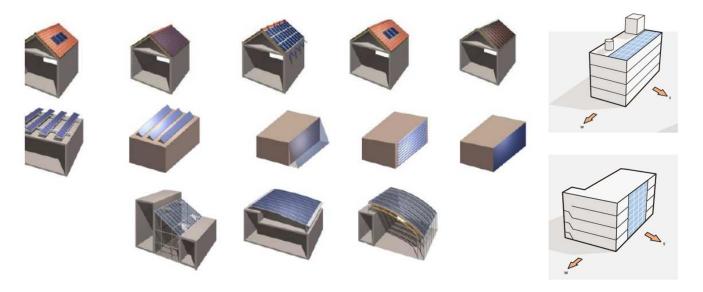








- BIPV (Building Integrated Photovoltaics):
  - PV systems integrated into the building envelope elements, such as construction materials as roof tiles and ceramic or glass facades.









#### Some BIPV examples.



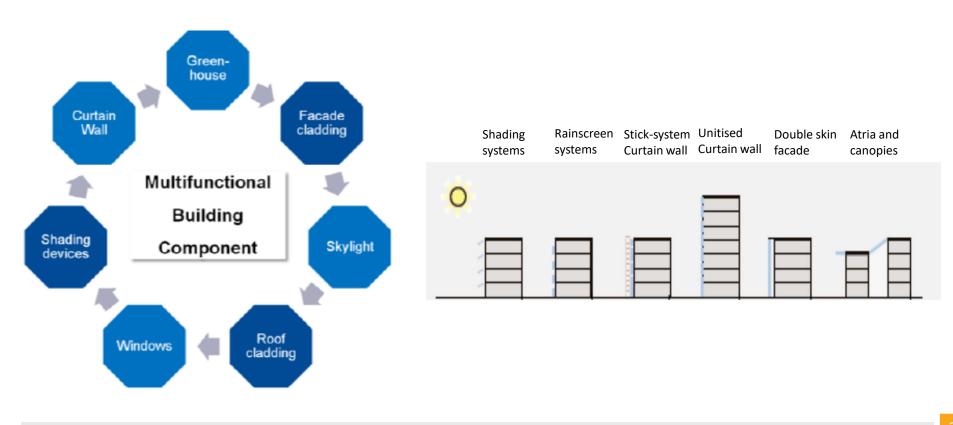
SolarBuildingTech, n.d.; Schüco, 2014







# **BIPV** applications



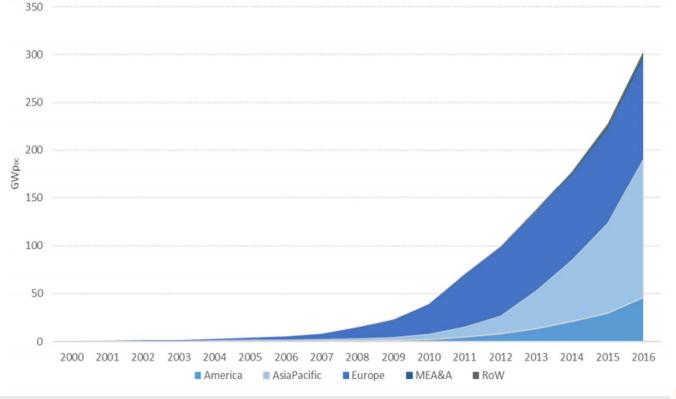






### Market development for BIPV

Low penetration in the overall PV market but as PV technology becomes mature and the cost/performance balance is steadily improving, integration into buildings is steadily encouraged especially in the concept of NZEBs.



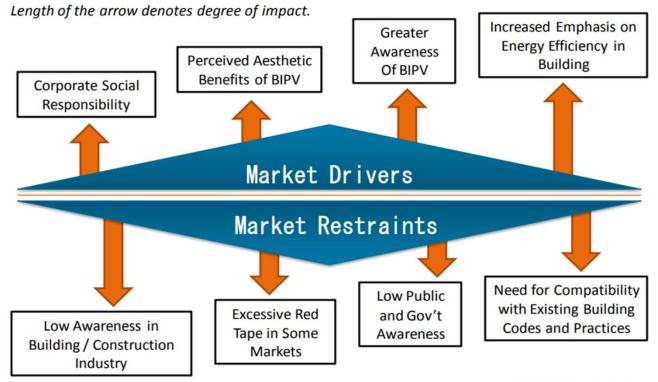
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#### Market drivers for BIPV



SOURCE: Frost & Sullivan







# **BIPV** multi-functionality

Main functions to take over from conventional construction materials:

- Moisture protection
- Insulation
- Heating
- Cooling
- Managing natural lighting
- Sunscreens
- Limited transmittance (semi-transparent)
- Etc.



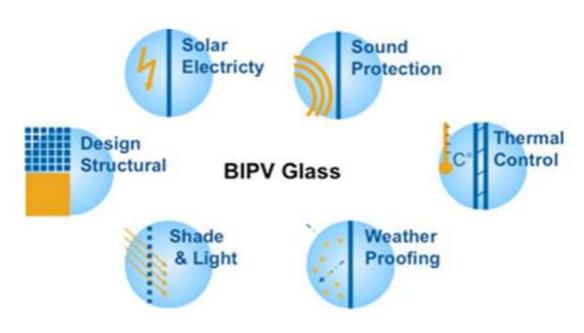






# **BIPV** multi-functionality

- BAPV less complicated
- BIPV take into account:
  - Requirements of construction materials (insulation, ventilation, etc.)
  - Architectural design
  - Optimal conditions for energy production
  - Financial aspects
  - Buildings regulations



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# **BIPV** multi-functionality

- Secondary functions: Design/Aesthetics
- To 'enhance' architectural appearance → Architects making a stronger statement!



PV-sunscreen (BISEM, 2012)



DSD PV: PV modules partly covered with a full color print (ECN).







### Advantages of BIPV

- Lower costs (considering that a building element is replaced)
- No rural/unoccupied area required
- Electrically self-sufficient
- Lower electricity losses
- Increased aesthetics
- Decreased heat-transmittance
- Decreased harmful irradiance
- Internal shading
- Creating awareness for BIPV
- Interesting marketing-strategy

- Improved internal environment  $\rightarrow$  comfort!







## Advantages of BIPV

• Ideal for use in the dense urban landscape

Available Roof Surface						
	Net Available Solar Surface (Km²)	Installable PV "Potential" (GW)	Estimated Electricity production (Twh/year)	Residential Electricity consumption 2006 (TWh/year)	% of PV	
Europe (75%: Germany, France, UK, Italy, Spain)	3.723	465,4 (8m²/Kwp)	511,9	859	59%	
		161,9 (23m²/KWp)	178,1		20%	
USA	4.563	570,4 (8m²/Kwp)	570,4	1351	42%	
		198,4(23m ² /KWp)	198,4		14%	
Japan	1.050	131,3 (8m²/Kwp)	118,1	229	51%	
		45,7 (23m ² /KWp)	41,1		18%	

Table I. Potential of BIPV (Source: D. Fraile Montoro, 2008)*.

*Facades not included.







# Disadvantages/barriers of BIPV

- Lower electricity performance (non-optimal orientations, thin-films, etc).
  - Cell-efficiency reduction
  - Compensation with more installation space on buildings apart from roof
- (Partial)-shading
- BIPV is experienced as 'too difficult'
  - Shortage of specialists
- Critics on aesthetics







# Legal, admin & market barriers

#### BIPV not new (more than 20 years!) $\rightarrow$ But still: under-developed niche

#### Legal & administrative barriers:

Not yet defined as energy-efficient technology in many places
 → complex planning policies & procedures (e.g. not possible on most historic buildings)

#### Market barriers:

- **Costly** compared to BAPV (added value as **multifunctional building element not recognized** yet)
- 'Language' problem between PV industry and building sector: different units of measurement e.g. architects/planners: kWh/m2 but PV community: kWh/KWp (not familiar with concept of watt power, prefer estimation of PV module price \$/m2)
- Perception obstacle: Advantages for architects and end-users not clearly defined; don't see it as valuable asset; don't see it as aesthetically-pleasing; lack of information?







### **Technical barriers**

- Predominant use of mature yet costly c-Si in envelopes (at minimal sunlight & high temperatures → poor performance).
- Thin-film challenges: Optimal system orientation, weather ability, lifetime, lack of standards/building codes, performance, competitive pricing.









### **Technical barriers**

#### Lack of own/specific standards for BIPV:

- Combining functionality of building materials & PV → new standards should address materials/architectural/safety/electrical issues & long-term performance issues
- Complex as requirements for standards (e.g. buildings) are mostly related to a country or region → a BIPV manufacturer must comply with different standards depending on country of application

PV module standards	Building standards
IEC	ISO
International Electrotechnical	International Organization for
Commission	Standardization
CENELEC	CEN
European Commission for	European Committee for
Electrotechnical Standardization	Standardization



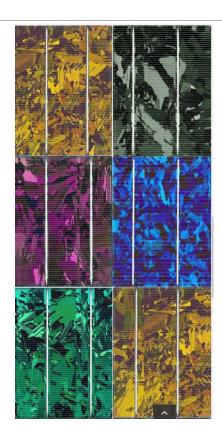




# BIPV products – Customisation

#### Characteristics:

- Material:
  - Crystalline, Thin-film, other
- Transparency:
  - Opaque, semi-transparent, transparent
- Colouring
- Shapes
- Sizes (cell, module)
- Distance between cells in a module
- Flexibility
- $\rightarrow$  Variety of customisation!









# BIPV products – Tiles









# BIPV products – Tiles (Vatican City)

- 1st PV plant for Vatican next to St. Peter's
- 2,394 dark solar modules cover roof of the 'Paolo VI' audience hall (221.59 KWp)
- The solar panels replaced the 4,800 degraded concrete tiles
- Rigid rules of Italian & International Restoration Chart.
- Optimal adaptation to the shape of the building challenging architectural design

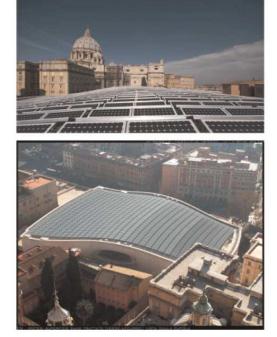


Figure 11. The BIPV plant on the roof of the Vatican 'Paolo VI' hall is magnificent example of philological restoration coupled to clean electricity generation. BIPV at its best. (Photo credit: energia e ambiente Srl).







# BIPV products – Full roof solution



Zanetti et al., 2017







### BIPV products – Solar cell glazing

- Options for windows, facades, roofs.
- Variety of materials and distances between cells.
- Different colours & transparencies
  - Variable transparency 10-50%
- Modules transmit daylight and serve as water and sun protection
  - E.g. greenhouse use
- Good efficiency in non-optimal positions
- Glass-glass frameless design for improved aesthetics







#### **Bifacial Flexible Module**



Source: https://www.pv-tech.org/products/jolywoods-bifacial-paving-module-boasts-front-power-of-430w-efficiency-of-2





#### Semi Transparent Modules



Source: https://www.pv-tech.org/products/solaria-provides-powervision-series-of-customized-architectural-glass-modul





#### **Glass Glass BIPV modules**



Source: https://www.pv-tech.org/products/aleo-solar-designs-elegante-monocrystalline-glass-glass-module-for-bipv-app

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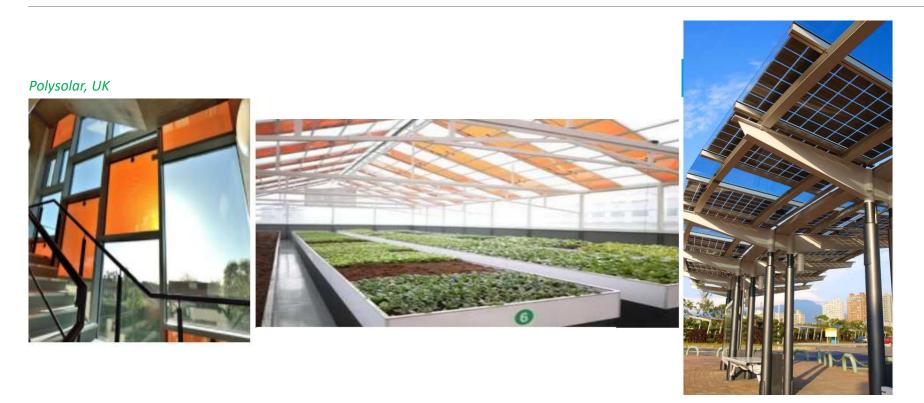
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#### BIPV products – Solar cell glazing



Kameleon solar







# BIPV products – Atria and canopies

 Canopies are similar to atria consisting of horizontal or gently inclined faces, high on a building.



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### **BIPV** products



Greenpix Zero Energy Media wall: The largest color **LED display** combined with a **PV-system** in the **glass curtain wall** 



#### CIS Tower in Manchester









### BIPV characteristics – Design life

- Design life of building envelopes and their components depends on the building use.
- Three types of elements must be considered:

#### • Replaceable elements:

intended to last less than the design life of the building and for which replacement has to be considered at design stage, e.g. double-glazed units (20–25 years). BIPV is in this type!

#### • Maintainable elements:

intended to last the design life of the building with periodic treatment and maintenance, e.g. weathering gaskets.

#### • Lifelong elements:

intended to last the design life of the building without maintenance, e.g. cladding framing members.







### **BIPV characteristics – Safety**

- Safety is a standard consideration with all electrical installations.
- Contact with the front surfaces of PV modules poses no danger.
- Particular issues that apply to PV installations:
  - Current is produced during a wide variety of light conditions (PV modules can only be "switched off" by covering with something opaque).
  - Less familiarity within the building industry with DC compared with AC.
  - Voltages can be higher than the familiar 230 V single-phase AC.
- Safety issues should be well documented for both installers and maintenance personnel.







#### BIPV characteristics – Acoustic performance

- Primarily a function of the glazing mass and composition, and the quality of the internal seals to stop air leakage.
- Sound insulation of curtain walls can be improved by installing sound attenuating infill and making construction as airtight as possible.







# **BIPV** characteristics – Natural lighting

Amount of incoming natural light and visual contact with exterior defined by:

- Number of windows with incorporated cells.
- Number of cells incorporated in the windows.



Onyx, 2017

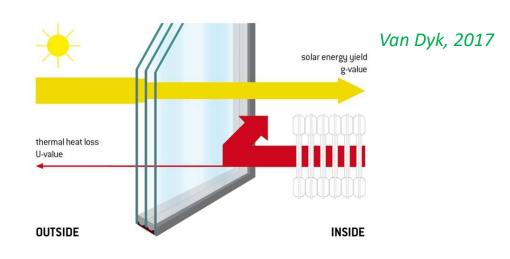






## BIPV characteristics – Thermal performance

- Building envelope needs to:
  - o mediate transfer of heat between internal and external environment.
  - o create a comfortable indoor environment while using the minimum amount of energy.
- Important parameters for the thermal performance:
  - U-value: Heat losses
  - o G-value: Solar heat gains









### BIPV characteristics – Air/Weather-tightness

- Building envelope: Air-tightness & Weather-tightness
  - Air-tightness:

The façade design should incorporate continuous air barriers to minimize air infiltration through the fabric.

• Weather-tightness:

A building facade needs to be weather-tight. Cladding design should incorporate multiple lines of defence against water ingress.

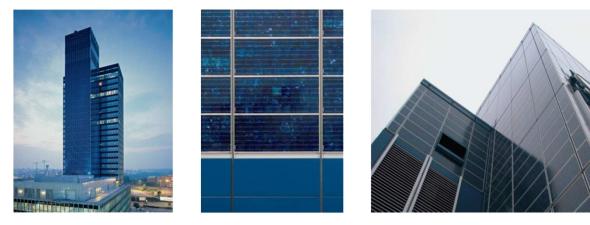






#### Case studies: Rainscreen systems

- The Co-operative Insurance Tower in the UK
- PV specifications:
  - Area: 3972 m²
  - Peak power specification: 391 kWp
  - Power output: 183,000 kWh/y (estimated)



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#### Case studies: Stick-system curtain wall

- Tobias Grau GmbH Head Office in Germany
- PV specifications:
  - Area: 179 m²
  - Peak power specification: 18 kWp
  - Power output: 10,800 kWh/y (estimated)









### Case studies: Unitised curtain wall

- Alan Gilbert Building in Australia
- PV specifications:
  - Area: 426 m²
  - Peak power specification: 46 kWp
  - Power output: 40,000 kWh/y (estimated)





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### Solar Roofs (Tesla/Solar City)



Source: https://www.pv-tech.org/products/tesla-solarcity-launches-multiple-styled-solar-roof-tiles-replicating-origi





#### Some more demo sites

https://www.pvsites.eu/project/demo-sites/

https://www.youtube.com/watch?v=4OG2C Vyxv8w

https://www.youtube.com/watch?v=fCzEm-ZrCuo







### Conclusions

- BIPV: PV elements used to replace conventional building materials in parts of the building envelope
- Increasingly being incorporated into new buildings as a source of electrical power.
- Advantage of BIPV over common non-integrated systems
  - The initial cost can be offset by reducing the amount spent on building materials and labour that would normally be used.
- Legal, admin, market & technical barriers inhibiting market development and expansion.
- Optimal method of installing RES in urban, built-up areas where underdeveloped land is scarce and expensive.
- Their widespread use is expected to become the backbone of European NZEB targets for 2020.





#### The value of PV!

#### https://www.youtube.com/watch?v=ckHVU7DKZAs







# Thank you for your attention!

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